Signal Processing with Silicon-Organic Hybrid Waveguides

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Abstract: The silicon-organic hybrid (SOH) platform is reviewed. The SOH approach is a promising CMOS compatible photonic platform enabling ultrafast nonlinear signal processing in compact silicon photonic devices.

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1. Introduction

Silicon photonics holds promise for convergence of photonic and electronic integrated circuit on one CMOScompatible platform. It has become a likely path towards cost-effective mass-producible, ultra-compact and power efficient multi-functional optoelectronic integrated circuits [1]-[4]. And while the field has made tremendous progress in recent years, electrical and optical modulation is still an issue. As a matter of fact, electrical and optical signal processing suffer from two-photon absorption (TPA) and free carrier absorption (FCA) related speed limitations, which require special measures to keep such speed limitations within limits.

In this paper, we review the silicon-organic hybrid (SOH) platform [5]. The SOH platform combines the advantages of silicon with the ultra-fast performance of organic Kerr $(\chi^{(3)})$ and electro-optic $(\chi^{(2)})$ nonlinear materials. In the SOH approach the silicon wire guides the optical modes but the necessary nonlinearity for switching is provided by an organic cladding. By a proper choice of the organic material optimum material parameters for the respective application can be chosen. This approach has recently led to demonstrations of 120 Gbit/s to 10 Gbit/s [6], 170 Gbit/s to 43 Gbit/s TDM demultiplexing [7], and 40 and 56 Gbit/s RZ and DQPSK wavelength conversion [8]-[10]. More recently, electro-optic switching has been predicted [14]-[17] and confirmed by experiments [18][19]. The electrooptic SOH approach however is not in the focus of this paper.

2. The Silicon Organic Hybrid (SOH) Platform

In the SOH approach, all active and passive waveguides, couplers and filters, are fabricated as silicon waveguides, see Fig. 1. Nonlinear optical functionality, however, is due to an organic cladding material.

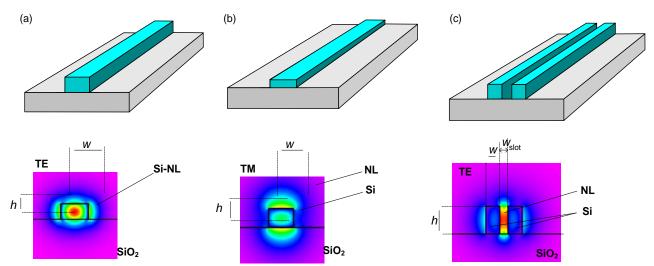


Fig. 1 Waveguide structures and electric field amplitudes of three silicon-wire structures. (a) The conventional silicon strip waveguide providing core nonlinearity from silicon for high-power TE signals, (b) Cover nonlinear waveguide in form of a strip waveguide where an organic cladding provides large nonlinearity to a TM signal, and (c) cover nonlinearity in a slot waveguide where an organic material provides strong nonlinearity to a TE-polarized signal.

In the more conventional approach depicted in Fig. 1(a), the dimensions of a silicon strip-waveguide have been chosen to provide a maximum confinement of the optical mode. This way the silicon nonlinearity with a nonlinear index coefficient n_2 =6 x 10⁻¹⁸ m²/W may be exploited. In the structure of Fig. 1(b) the silicon waveguide provides guiding but is designed to push the optical mode as far as possible into the cladding layer above the waveguide. As a nonlinear material we have chosen the organic molecule DDMEBT with a nonlinear coefficient n_2 =2 x 10⁻¹⁷ m²/W [11]. A further improvement is obtained with the slot-waveguide structure from Fig. 1(c). Here the optical mode is mostly confined to the narrow slot. The field enhancement across the slot is maximum [11].

Next we compare the nonlinearities of the three waveguide structures depicted in Fig. 2. An in-depth discussion may be found in Ref. [12] and [13]. The strength of the Kerr nonlinearity is best described by the nonlinearity coefficient γ . The nonlinearity coefficient γ can be maximized by using materials with a strong nonlinear index coefficient n_2 and the smallest possible third-order nonlinear effective interaction area. The nonlinearity coefficient γ has been plotted for the three structures in Fig. 2. At first sight it looks as if structure (a) with core nonlinearity has the highest nonlinearity. Yet, the nonlinearity coefficient does not tell all. The efficiency – and even worse the ultrafast short time constants might be impeded by TPA (two-photon absorption). In the presence of large TPA free carriers are generated in the conduction and valence band. These carriers in turn lead to plasma effect related free carrier refractive index and absorption changes. As the free carrier lifetimes are long (up to several 100 ns) the overall speed of such structures might be at risk. The bottom part of Fig. 2 shows the evolution of the pump light-induced phase change in the respective three structures in pump-probe experiments While the core nonlinear structure shows a large Kerr-effect it also shows a TPA-induced large plasma effect-related tail with a large time constant. The slot nonlinear structure on the other hand has both a large Kerr effect and no visible plasma effect-related tail. In literature, a figure of merit (FOM) is often used to compare the magnitude of the Kerr coefficient n_2 with the strength of the TPA coefficient α_2 . This FOM is defined as FOM= $n_2/(\lambda \alpha_2)$. From our experiments we know that its value should be 0.5 or larger. Table 1 summarizes the results.

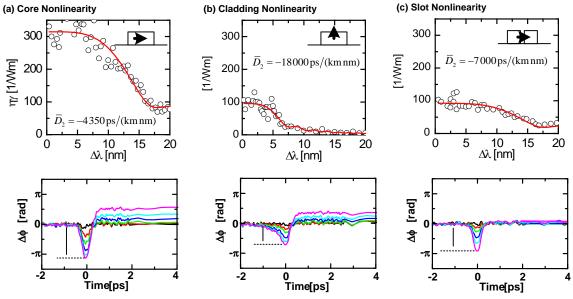


Fig. 2 (Upper row) Dependence of the nonlinearity parameter $\operatorname{Re}\{\gamma\}$ times η , the normalized four-wave mixing efficiency, as a function of the wavelength detuning $\Delta\lambda$; measurement (°) and fit (-). η describes the normalized degradation of the four-wave mixing efficiency with increasing phase mismatch, for perfect phase-matching $\eta=1$ holds. (Lower row) Pump light-induce phase change $\Delta\phi$ dynamics of the highly nonlinear waveguides for different pump power levels. Only the slot-nonlinear structure shows no TPA impeded slow phase dynamics.

Table 1: Summary of waveguide parameters of the three structures.

Design	Core	Cladding	Slot
$\gamma [1/(W \text{ km})]$	307 000	108 000	100 000
FOM _{TPA}	0.38	1.21	2.19
Height [nm]	220	220	220
RibWidth [nm]	360400	360400	220
SlotWidth [nm]	-	•	160200

4. Nonlinear Signal Processing with Silicon Organic Hybrid Waveguide Structures

To show the viability of the approach we give some examples of signal processing experiments performed with silicon organic hybrid waveguides. For instance, all-optical demultiplexing from 120 Gbit/s to 10 Gbit/s and 170 Gbit/s to 43 Gbit/s [7] has been shown in a slot-waveguide of 4 mm length. More recently, 40 Gbit/s RZ and 56 Gbit/s DQPSK all-optical wavelength conversion based on the nonlinear FWM process as well as 43 Gbit/s all-optical wavelength conversion exploiting XPM nonlinearities have been demonstrated [8]-[10]. The scheme and the eye diagrams of the most recent all-optical wavelength conversion experiments are depicted in Fig. 3.

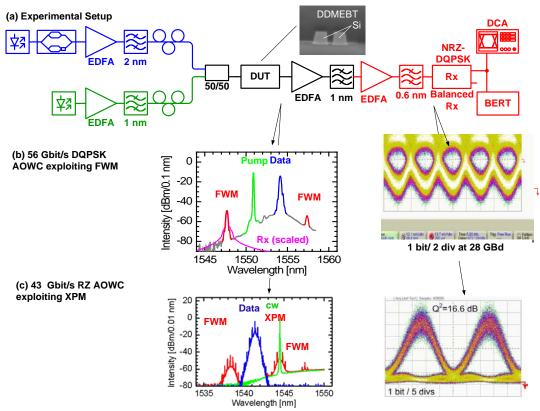


Fig. 3 All-optical wavelength conversion with the silicon-organic hybrid approach. (a) Experimental setup, (b) 56 Gbit/s all-optical DQPSK wavelength conversion exploiting the FWM nonlinear effect. (c) 43 Gbit/s all-optical RZ wavelength conversion exploiting the XPM nonlinear effect.

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